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=> FILE HCAPL

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This file contains CAS Registry Numbers for easy and accurate
substance identification.

=> D QUE

L6 2117 SEA FILE=HCAPLUS ABB=ON (TWO OR SECOND OR 2ND OR 2) (2A) POLYMER
?(2A) LAYER?
L7 6696 SEA FILE=HCAPLUS ABB=ON (MULTILAYER? OR BILAYER?) (2A) POLYMER?
L8 1030 SEA FILE=HCAPLUS ABB=ON (ONE OR FIRST OR 1ST) (2A) POLYMER? (2A) L
AYER?
L9 559 SEA FILE=HCAPLUS ABB=ON ((L6 AND L8) OR L7) AND METAL? (2A) ?LAY

KATHLEEN FULLER EIC1700 571/272-2505

ER?
L11 66 SEA FILE=HCAPLUS ABB=ON L9 AND (ANOD? OR ELECTRODE?)
L15 19 SEA FILE=HCAPLUS ABB=ON L11 AND ELECTROCHEM?/SC,SX
L22 319 SEA FILE=HCAPLUS ABB=ON L9 AND (PP OR POLYPROPYLENE OR PE OR
POLYETHYLENE OR POLYAMIDE? OR POLYIMIDE? OR POLYOLEFIN? OR
POLYESTER? OR POLYACETAL? OR POLYCARBONATE? OR POLYSULFON? OR
PVC OR POLYVINYLCHLORIDE OR ETHYLENE(W)VINYL)
L23 24 SEA FILE=HCAPLUS ABB=ON L22 AND (ANOD? OR ELECTRODE?)
L55 8 SEA FILE=HCAPLUS ABB=ON L15 AND ELECTROCHEMICAL?/SC,SX
L56 24 SEA FILE=HCAPLUS ABB=ON L23 OR L55

=> D L56 BIB ABS IND HITSTR 1-24

L56 ANSWER 1 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN
AN 2007:845915 HCAPLUS Full-text
DN 147:201821
TI Multilayer strip-line capacitor components for preventing electromagnetic
wave leakage
IN Masuda, Koichiro
PA NEC Corporation, Japan
SO PCT Int. Appl., 46pp.
CODEN: PIXXD2
DT Patent
LA Japanese
FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	WO 2007086210	A1	20070802	WO 2006-JP325222	20061219
	W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, SV, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW				
	RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM				

PRAI JP 2006-15864 A 20060125

AB The title capacitor components comprise multiple cylindrical metal pieces with
different sizes, and the cylindrical metal pieces are disposed as multilayer
around a strip-shaped metal piece. Dielec. films and conductive layers are
disposed between the innermost one of the multiple cylindrical metal pieces
and the strip-shaped metal piece and they are between mutually adjacent
cylindrical metal pieces. The dielec. films and the conductive layers are
also disposed as multilayer in sym. positional relations with respect to the
side wall portions of the individual cylindrical metal pieces.

CC 76-10 (Electric Phenomena)

ST multilayer strip line capacitor component electromagnetic wave leakage
prevention

IT Oxidation

(anode; multilayer strip-line capacitor components for
preventing electromagnetic wave leakage)

IT Etching

(capacitive component fabrication; multilayer strip-line capacitor
components for preventing electromagnetic wave leakage)

IT Dielectric films

KATHLEEN FULLER EIC1700 571/272-2505

- (capacitor; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Conducting **polymers**
(conducting layers; **multilayer** strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Lamination
(conductive layer, graphite, and Ag paste; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Polyanilines
RL: TEM (Technical or engineered material use); USES (Uses)
(conductive **polymers**; **multilayer** strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Electric apparatus
(decoupling components; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Films
(elec. conductive; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Electric conductors
(films; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Electromagnetic wave
(leakage prevention; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Electromagnetic shields
Polymerization
Semiconductor device fabrication
(**multilayer** strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Capacitors
(multilayer, nonpolar, electrolytic; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Films
(multilayer; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT Pastes
(silver, conducting layers; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT 11128-98-6, Ammonium borate
RL: NUU (Other use, unclassified); RCT (Reactant); RACT (Reactant or reagent); USES (Uses)
(**anode** oxidation; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT 7782-42-5, Graphite, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(conducting layers; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT 126213-51-2, **Polyethylene** dioxy thiophene
RL: TEM (Technical or engineered material use); USES (Uses)
(conductive layer, doped with dodecyl benzene sulfonic acid; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)
- IT 25233-34-5, Polythiophene 30604-81-0, Polypyrrole
RL: TEM (Technical or engineered material use); USES (Uses)
(conductive **polymers**; **multilayer** strip-line capacitor components for preventing electromagnetic wave leakage)
- IT 1344-28-1, Aluminum oxide, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(dielec. film; multilayer strip-line capacitor components for preventing electromagnetic wave leakage)

IT 27176-87-0, Dodecyl benzene sulfonic acid
 RL: CAT (Catalyst use); MOA (Modifier or additive use); USES (Uses)
 (dopant to **polyethylene** dioxy thiophene; multilayer
 strip-line capacitor components for preventing electromagnetic wave
 leakage)

IT 116-15-4, Hexafluoropropylene
 RL: NUU (Other use, unclassified); PEP (Physical, engineering or chemical
 process); PROC (Process); USES (Uses)
 (mask **polymer**; **multilayer** strip-line capacitor
 components for preventing electromagnetic wave leakage)

IT 7429-90-5, Aluminum, uses 7440-03-1, Niobium, uses 7440-25-7,
 Tantalum, uses 7440-32-6, Titanium, uses
 RL: TEM (Technical or engineered material use); USES (Uses)
 (**metal** pieces; **multilayer** strip-line capacitor
 components for preventing electromagnetic wave leakage)

IT 109-99-9, Tetrahydrofuran, uses
 RL: NUU (Other use, unclassified); RCT (Reactant); RACT (Reactant or
 reagent); USES (Uses)
 (removing mask **polymer**; **multilayer** strip-line
 capacitor components for preventing electromagnetic wave leakage)

RE.CNT 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD
 ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 2 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2007:750095 HCAPLUS Full-text

DN 147:147185

TI Method for manufacturing packaging structure for energy storage device

IN Wang, Fu-Min; Chiang, Pin-Chi; Wu, Mao-Sung; Lee, Chih-Tsung

PA Industrial Technology Research Institute of Taiwan, Taiwan

SO Faming Zhuanli Shenqing Gongkai Shuomingshu, 23pp.

CODEN: CNXXEV

DT Patent

LA Chinese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	CN 1992375	A	20070704	CN 2005-10132981	20051231
PRAI	CN 2005-10132981		20051231		

AB The title method comprises providing a **first polymer layer**, electroplating a
 first **metal layer** on one side of the **first polymer layer**, providing a first
 adhesive layer on the first **metal layer**, and adhering a **second polymer layer**
 on the first adhesive layer. The first and second polymers can be same or
 different, and are selected from **polyethylene** terephthalate (PET), cast
polypropylene (CPP) or oriented **polypropylene** (OPP). The method for
 manufacturing energy storage device further comprises placing pos. and neg.
electrode plates and a diaphragm between two sheet of packaging structures,
 injecting electrolyte, vacuum-sealing the packaging structures by hot
 pressing, and activating. The inventive energy storage device has high
 flexibility, high functionality, and high safety.

CC 52-2 (**Electrochemical**, Radiational, and Thermal Energy
 Technology)

Section cross-reference(s): 35, 59, 76

ST packaging structure energy storage device safety

IT Secondary batteries

(lithium; method for manufacturing packaging structure for energy storage
 device)

IT **Electrodeposition**

Electronic packaging process

Energy storage systems

Fuel cells

Safety
 Secondary batteries
 (method for manufacturing packaging structure for energy storage device)

IT Metals, uses
Polyesters, uses
 RL: PRP (Properties); TEM (Technical or engineered material use); USES
 (Uses)
 (method for manufacturing packaging structure for energy storage device)

IT Electrolytic capacitors
 (supercapacitors; method for manufacturing packaging structure for energy
 storage device)

IT 9003-07-0, **Polypropylene** 25038-59-9, uses
 RL: PRP (Properties); TEM (Technical or engineered material use); USES
 (Uses)
 (method for manufacturing packaging structure for energy storage device)

IT 7439-93-2, Lithium, uses
 RL: TEM (Technical or engineered material use); USES (Uses)
 (method for manufacturing packaging structure for energy storage device)

L56 ANSWER 3 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2007:415608 HCAPLUS Full-text

DN 146:465244

TI All-solid-state thin film lithium battery and its manufacture

IN Yu, Aishui; Wang, Weijiang; Wu, Haoqing

PA Fudan University, Peop. Rep. China

SO Faming Zhuànli Shenqing Gongkai Shuomingshu, 20pp.

CODEN: CNXXEV

DT Patent

LA Chinese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	CN 1945881	A	20070411	CN 2006-10117899	20061102
PRAI	CN 2006-10117899		20061102		

AB The battery has a solid electrolyte film between a cathode film and an **anode** film, a collector film connected to the cathode film and the and the **anode** film, and a packaging material; wherein the cathode material is selected from LiCoO₂, V₂O₅, or LiMn₂O₄; the **anode** material is selected from carbon material Sn_Nx or Li; the solid electrolyte is LiPON, the collector connected to the cathode and the **anode** is a metal film, and the packaging material is a **metal/polymer composite multilayered** film. The battery is manufactured by cleaning a substrate, preparing a cathode collector by d.c. sputtering process with Au as target, preparing a cathode by radio frequency magnetron sputtering at a power of 100-500 W and a rate of 0.2-3 μ/h under 10⁻³-10⁻⁵ Pa in an oxygen gas atmospheric at a gas flow rate of 10-50 sccm, depositing a LiPON inorg. electrolyte on the cathode film by radio frequency sputtering in nitrogen gas to obtain a solid electrolyte, preparing an **anode** by vacuum depositing under 10⁻³-10⁻⁵Pa in argon gas, connecting a **metal layer** to the cathode and the **anode** by welding or metal sol, and sealing with the packaging film. A. The inventive batteries has stable interface between electrolytes and **electrodes**, good resistance to high temperature and pressure, high capacity and excellent cycle performance.

CC 52-2 (**Electrochemical**, Radiational, and Thermal Energy Technology)

ST secondary lithium battery manuf solid electrolyte

IT Battery **electrodes**

Battery electrolytes

Secondary batteries

(structure and manufacture of all-solid-state secondary lithium batteries)

IT 1314-62-1, Vanadium oxide (V₂O₅), uses 7429-90-5, Aluminum, uses

KATHLEEN FULLER EIC1700 571/272-2505

7439-93-2, Lithium, uses 9002-88-4, **Polyethylene** 9003-07-0,
Polypropylene 10377-52-3, Lithium phosphate 12057-17-9,
 Lithium manganese oxide (LiMn2O4) 12190-79-3, Cobalt lithium oxide
 (CoLiO2) 25722-33-2, Parylene 55574-97-5, Tin nitride 668998-68-3,
 Lithium phosphorus nitride oxide (LiPNO)
 RL: TEM (Technical or engineered material use); USES (Uses)
 (structure and manufacture of all-solid-state secondary lithium batteries)

L56 ANSWER 4 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2007:330364 HCAPLUS Full-text

DN 146:366616

TI Multilayered nanostructured films for catalyst supports of increased surface area

IN Debe, Mark K.; Ziegler, Raymond J.; Hendricks, Susan M.

PA 3M Innovative Properties Company, USA

SO PCT Int. Appl., 48pp.

CODEN: PIXXD2

DT Patent

LA English

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	WO 2007032864	A2	20070322	WO 2006-US32703	20060823
	WO 2007032864	A3	20070510		
	W:	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HN, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, SV, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW			
	RW:	AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AP, EA, EP, OA			

PRAI US 2005-224879 A 20050913

AB Processes for forming films comprising multiple layers of nanostructured support elements are described. A 1st layer of nanostructured support elements is formed by depositing a base material on a substrate and annealing. Further growth of the 1st layer of nanostructures is then inhibited. Addnl. layers of nanostructured support elements may be grown on the 1st layer of nanostructures through addnl. deposition and annealing steps. The multilayer films provide increased surface area and are particularly useful in devices where catalyst activity is related to the surface area available to support catalyst particles.

IC ICM B82B

CC 67-2 (Catalysis, Reaction Kinetics, and Inorganic Reaction Mechanisms)
 Section cross-reference(s): 9, 52

ST multilayer nanostructure film catalyst support increased surface area

IT Porous materials

(catalyst substrates; multilayered nanostructured films for catalyst supports of increased surface area)

IT Printed circuit boards

(flexible; multilayered nanostructured films for catalyst supports of increased surface area)

IT Polyoxyalkylenes, uses

RL: CAT (Catalyst use); PEP (Physical, engineering or chemical process);
 PROC (Process); USES (Uses)

(fluorine- and sulfo-containing, ionomers; multilayered nanostructured

- films for catalyst supports of increased surface area)
- IT Membranes, nonbiological
(ionic conducting; multilayered nanostructured films for catalyst supports of increased surface area)
- IT Ionic conductors
(membranes; multilayered nanostructured films for catalyst supports of increased surface area)
- IT Annealing
Catalyst supports
Coating process
Electrodes
Fuel cell **anodes**
Fuel cell cathodes
Fuel cell **electrodes**
Multilayers
Nanostructures
Optical filters
Photoelectric devices
Sensors
(multilayered nanostructured films for catalyst supports of increased surface area)
- IT Acrylic **polymers**, uses
Metals, uses
Platinum-group **metals**
Polyimides, uses
RL: CAT (Catalyst use); PEP (Physical, engineering or chemical process);
PROC (Process); USES (Uses)
(**multilayered** nanostructured films for catalyst supports of increased surface area)
- IT Films
(nanostructured; multilayered nanostructured films for catalyst supports of increased surface area)
- IT Materials
(organic; multilayered nanostructured films for catalyst supports of increased surface area)
- IT Fluoropolymers, uses
RL: CAT (Catalyst use); PEP (Physical, engineering or chemical process);
PROC (Process); USES (Uses)
(polyoxyalkylene-, sulfo-containing, ionomers; multilayered nanostructured films for catalyst supports of increased surface area)
- IT Ionomers
RL: CAT (Catalyst use); PEP (Physical, engineering or chemical process);
PROC (Process); USES (Uses)
(polyoxyalkylenes, fluorine- and sulfo-containing; multilayered nanostructured films for catalyst supports of increased surface area)
- IT Fuel cells
(proton exchange membrane; multilayered nanostructured films for catalyst supports of increased surface area)
- IT 4948-15-6, Pigment Red 149 7440-06-4, Platinum, uses
RL: CAT (Catalyst use); PEP (Physical, engineering or chemical process);
PROC (Process); USES (Uses)
(multilayered nanostructured films for catalyst supports of increased surface area)

L56 ANSWER 5 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2007:27938 HCAPLUS Full-text

DN 146:283394

TI Dry formation of polymer hole injection layer for top emitting organic light emitting diodes

AU Seo, Soon-min; Kim, Jong H.; Lee, Hong H.

KATHLEEN FULLER EIC1700 571/272-2505

- CS School of Chemical and Biological Engineering, Seoul National University, Seoul, 151-742, S. Korea
- SO Applied Physics Letters (2006), 89(25), 253515/1-253515/3
CODEN: APPLAB; ISSN: 0003-6951
- PB American Institute of Physics
- DT Journal
- LA English
- AB Dry formation of polymer hole injection layer is introduced as an effective method for improving the performance of top emitting organic light emitting diodes (TOLEDs). This method involves transferring a **metal/polymer bilayer** to the surface of organic layers of the device by pressing. An added advantage of this method is the ability to pattern the **anode** in the transfer process. Fabrication of the inverted TOLED by this method results in a drastic reduction of the turn-on voltage, from 14.5 to 6.5 V, when compared with a reference
- CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
Section cross-reference(s): 76
- ST dry polymer hole injection top light emitting diode LED
- IT Polyurethanes, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(acrylates, mold; dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT Electric current-potential relationship
Electroluminescent devices
(dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT **Polyesters**, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT Energy level
(of layers for top emitting organic light emitting diodes)
- IT 155090-83-8, PEDOT-PSS
RL: TEM (Technical or engineered material use); USES (Uses)
(**anode** coating; dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT 7440-57-5, Gold, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(**anode**; dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT 123847-85-8, NPB
RL: TEM (Technical or engineered material use); USES (Uses)
(bilayer film; dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT 37626-13-4, AF 2400
RL: TEM (Technical or engineered material use); USES (Uses)
(coating; dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT 2085-33-8, Alq3
RL: TEM (Technical or engineered material use); USES (Uses)
(dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT 7429-90-5, Aluminum, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(**electrode**; dry formation of polymer hole injection layer for top emitting organic light emitting diodes)
- IT 25038-59-9, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(mold; dry formation of polymer hole injection layer for top emitting

organic light emitting diodes)

RE.CNT 14 THERE ARE 14 CITED REFERENCES AVAILABLE FOR THIS RECORD
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 6 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2006:944702 HCAPLUS Full-text

DN 145:343851

TI Multilayer protection film for rust prevention of metal materials

IN Nakamura, Noboru; Uchida, Nobuhiko

PA Kyocera Chemical Corp., Japan

SO Jpn. Kokai Tokkyo Koho, 10pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 2006241512	A	20060914	JP 2005-58175	20050302
PRAI	JP 2005-58175		20050302		

AB The film comprises a **metal layer** and an adhesive layer, or comprises a polymer film, a **metal layer**, and an adhesive layer, or comprises a polymer film and an adhesive layer containing **metal** powder, where the standard **electrode** potential of the **metal layer** or the **metal** powder is lower than that of the substrate metal material; and there is an elec. contact structure between the substrate metal material and the **metal layer** or the **metal** powder. Preferably, the substrate metal material is Fe; the **metal layer** or the **metal** powder is Zn, Al, Mg, and/or their alloy; and there are unevenness on the **metal layer** surface with its concavity being in contact with the adhesive layer.

CC 72-6 (Electrochemistry)

Section cross-reference(s): 38, 55, 56

ST multilayer protection film rust prevention metal material; zinc aluminum magnesium **polymer** adhesive **multilayer** protection film

IT Acrylic polymers, uses

RL: NUU (Other use, unclassified); TEM (Technical or engineered material use); USES (Uses)

(adhesive layer; of multilayer protection film for rust prevention of metal materials)

IT Coating materials

(anticorrosive; multilayer protection film for rust prevention of metal materials)

IT Coating materials

(multilayer protection film for rust prevention of metal materials)

IT **Metals**, uses

RL: PRP (Properties); TEM (Technical or engineered material use); USES (Uses)

(**multilayer** protection film for rust prevention of metal materials)

IT Films

(multilayer; multilayer protection film for rust prevention of metal materials)

IT 7429-90-5, Aluminum, uses 7439-95-4, Magnesium, uses 7440-66-6, Zinc, uses

RL: NUU (Other use, unclassified); TEM (Technical or engineered material use); USES (Uses)

(**metal layer**; of **multilayer** protection film for rust prevention of metal materials)

IT 9003-07-0, **Polypropylene**

RL: NUU (Other use, unclassified); TEM (Technical or engineered material use); USES (Uses)

(**polymer** film; of **multilayer** protection film for

rust prevention of metal materials)

IT 7439-89-6, Iron, uses

RL: PRP (Properties); TEM (Technical or engineered material use); USES (Uses)

(substrate; multilayer protection film for rust prevention of metal materials)

L56 ANSWER 7 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2006:144677 HCAPLUS Full-text

DN 144:195326

TI Outer case members for secondary batteries for prevention of internal short circuits at wider temperature range

IN Yamamura, Akira

PA Nissan Motor Co., Ltd., Japan

SO Jpn. Kokai Tokkyo Koho, 12 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 2006049219	A	20060216	JP 2004-231451	20040806
PRAI	JP 2004-231451		20040806		

AB The members, for keeping and sealing power generation members, include **metal layers, first polymer inner layers** (e.g., **polypropylene**), and **second polymer inner layers** (e.g., **polyethylene**), satisfying $T_{1p} > T_{2p}$ and $T_{2g} < T_{1g}$ (T_{1p} , T_{2p} = m.p. of the **first and second polymer inner layers**, resp.; T_{1g} , T_{2g} = Tg of the **first and second polymer inner layers**, resp.). The secondary batteries show no p.d. between the **metal layers** and cathode and **anode** terminals after storage at low and high temps., and no self heat generation after overheating.

CC 52-2 (**Electrochemical**, Radiational, and Thermal Energy Technology)

Section cross-reference(s): 38

ST outer case battery prevention internal short circuit; metal polymer laminate outer case battery; **polypropylene polyethylene** aluminum alloy laminate battery case

IT Secondary batteries

(outer case members including **metal layers** and **first and second polymer inner layers** for secondary batteries)

IT Aluminum alloy, base

RL: DEV (Device component use); USES (Uses)

(**metal layer**; outer case members including

metal layers and **first and second**

polymer inner layers for secondary batteries)

IT 9003-07-0, **Polypropylene**

RL: DEV (Device component use); USES (Uses)

(first inner layer; outer case members including **metal layers** and **first and second polymer**

inner layers for secondary batteries)

IT 9002-88-4, **Polyethylene**

RL: DEV (Device component use); USES (Uses)

(second inner layer; outer case members including **metal layers** and **first and second polymer**

inner layers for secondary batteries)

L56 ANSWER 8 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2005:1142150 HCAPLUS Full-text

DN 144:83377

KATHLEEN FULLER EIC1700 571/272-2505

TI Multilayer Laminated **Electrode** Assemblies: Integrated Disposable Sampling-Sensing Structures

AU Yonge, Laura; Isaac, Anita; Livingstone, Callum; Davis, James

CS School of Biomedical and Natural Sciences, Nottingham Trent University, Nottingham, UK

SO Analytical Letters (2005), 38(13), 2067-2076
CODEN: ANALBP; ISSN: 0003-2719

PB Taylor & Francis, Inc.

DT Journal

LA English

AB A novel approach to the use and fabrication of disposable electrochem. sensors has been detailed. Metal foils are sandwiched between an insulating polymer with multiple, individually addressable layers built up to form the basis of a three-**electrode** sensor. Coring the laminate reveals a ring **electrode** configuration within a "detection well" with sample volume defined by the capillary filling of the void. A dip-extract-analyze sampling protocol was designed such that multiple sites within a single laminate strip can be used. The mech. integrity of the construction has been assessed by electron microscopy and the electrochem. characteristics investigated using the oxidation of glucose as a model analyte. The reproducibility of the fabrication method has been evaluated with intra- and inter-RSD values for the anal. of 2 mM glucose lying within 5%.

CC 9-7 (Biochemical Methods)

ST **metal polymer multilayer electrode**
voltammetry; glucose sensor copper foil **polyester** multilayer **electrode**

IT Sensors
(electrochem.; multilayer laminated **electrode** assemblies for integrated disposable sampling-sensing structures)

IT Cyclic voltammetry
Electrodes
Glucose sensors
Lamination
Linear-sweep voltammetry
Multilayers
(multilayer laminated **electrode** assemblies for integrated disposable sampling-sensing structures)

IT **Polyesters**, analysis
RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST (Analytical study); USES (Uses)
(multilayer laminated **electrode** assemblies for integrated disposable sampling-sensing structures)

IT **Electrodes**
(ring; multilayer laminated **electrode** assemblies for integrated disposable sampling-sensing structures)

IT Electric insulators
Foils
Sampling
(three-**electrode** sensor built of metal foils sandwiched between insulating polymer with multiple, individually addressable layers)

IT Metals, analysis
Polymers, analysis
RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST (Analytical study); USES (Uses)
(three-**electrode** sensor built of metal foils sandwiched between insulating polymer with multiple, individually addressable layers)

IT 50-99-7, Glucose, analysis
RL: ANT (Analyte); ANST (Analytical study)

(multilayer laminated **electrode** assemblies for integrated disposable sampling-sensing structures)

IT 7440-50-8, Copper, analysis

RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST (Analytical study); USES (Uses)

(multilayer laminated **electrode** assemblies for integrated disposable sampling-sensing structures)

RE.CNT 13 THERE ARE 13 CITED REFERENCES AVAILABLE FOR THIS RECORD
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 9 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2004:1051697 HCAPLUS Full-text

DN 142:209797

TI Manufacturing wafer-level chip-scale-package to absorb stress generated due to difference of thermal expansion

IN Jang, Dong Hyeon; Kang, Sa Yun

PA Samsung Electronics Co., Ltd., S. Korea

SO Repub. Korean Kongkae Taeho Kongbo, No pp. given

CODEN: KRXXA7

DT Patent

LA Korean

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	KR 2001105641	A	20011129	KR 2000-26313	20000517
PRAI	KR 2000-26313		20000517		

AB A wafer-level chip-scale-package (WL-CSP) is provided to absorb stress generated according to a difference of thermal expansion between the WL-CSP and a system board where the WL-CSP is mounted, by forming the **first polymer layer** composed of elastomer directly formed on a passivation layer and photosensitive **polyimide** (PSPI). A passivation layer is formed on a side surface of a semiconductor substrate having **electrode** pads exposed between passivation layers. The **first polymer layer** is formed on the passivation layer. A under barrier metal (UBM) of a predetd. pattern is formed on the **electrode** pad and the **first polymer layer**. A metal redistribution layer is formed on the UBM, elec. connected to the **electrode** pad. The **second polymer layer** is formed on the **first polymer layer** and the redistribution layer. An outer connector is formed on a portion of the redistribution layer exposed between the **second polymer layers**, elec. connected to the **electrode** pad. The **first polymer layer** includes elastomer directly formed on the passivation layer so that stress transferred through the outer connector is absorbed by the elastomer.

IC ICM H01L023-52

CC 76-3 (Electric Phenomena)

ST wafer level chip scale package stress damping passivation

electrode

IT **Electrodes**

Electronic packages

Passivation

Semiconductor materials

Thermal expansion

(manufacturing wafer-level chip-scale-package to absorb stress generated due to difference of thermal expansion)

IT **Polyimides**, processes

RL: CPS (Chemical process); PEP (Physical, engineering or chemical process); TEM (Technical or engineered material use); PROC (Process); USES (Uses)

(photosensitive; manufacturing wafer-level chip-scale-package to absorb stress generated due to difference of thermal expansion)

L56 ANSWER 10 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2004:1036523 HCAPLUS Full-text

DN 142:9264

TI **Anode** for rechargeable lithium battery

IN Cho, Chung-Kun; Hwang, Duck-Chul; Hwang, Seung-Sik; Lee, Sang-Mock

PA Samsung SDI Co., Ltd., S. Korea

SO U.S. Pat. Appl. Publ., 9 pp.

CODEN: USXXCO

DT Patent

LA English

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	US 2004241549	A1	20041202	US 2004-776229	20040212
	KR 2004102436	A	20041208	KR 2003-33819	20030527
	JP 2004356082	A	20041216	JP 2003-359504	20031020
	CN 1574424	A	20050202	CN 2004-10047713	20040305
PRAI	KR 2003-33819	A	20030527		

AB The **anode** comprises a first polymer layer, a second polymer layer on the first polymer layer, a metal layer on the second polymer layer and an **anode** active material layer on the metal layer.

IC ICM H01M002-16

ICS H01M004-66; H01M004-40

INCL 429246000; 429245000; 429231950

CC 52-2 (Electrochemical, Radiational, and Thermal Energy Technology)

Section cross-reference(s): 38, 49

ST secondary lithium battery **anode**

IT Battery **anodes**

Laminated materials

(**anodes** for secondary lithium batteries)

IT Fluoropolymers, uses

Polyamides, uses

Polycarbonates, uses

Polyesters, uses

Polyimides, uses

Polyolefins

Polyoxyalkylenes, uses

Polyoxymethylenes, uses

Polysulfones, uses

RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)

(**anodes** for secondary lithium batteries)

IT Polysiloxanes, uses

RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)

(aralkyl, halo; **anodes** for secondary lithium batteries)

IT Coating process

(gap, knife, slot-die; **anodes** for secondary lithium batteries)

IT Secondary batteries

(lithium; **anodes** for secondary lithium batteries)

IT Alkadienes

RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)

(polymers; **anodes** for secondary lithium batteries)

IT Coating process

(roller; **anodes** for secondary lithium batteries)

KATHLEEN FULLER EIC1700 571/272-2505

IT Coating process
(spray; **anodes** for secondary lithium batteries)

IT 7429-90-5, Aluminum, uses 7439-89-6, Iron, uses 7439-92-1, Lead, uses 7439-93-2, Lithium, uses 7439-95-4, Magnesium, uses 7439-98-7, Molybdenum, uses 7440-02-0, Nickel, uses 7440-06-4, Platinum, uses 7440-09-7, Potassium, uses 7440-21-3, Silicon, uses 7440-22-4, Silver, uses 7440-23-5, Sodium, uses 7440-24-6, Strontium, uses 7440-32-6, Titanium, uses 7440-33-7, Tungsten, uses 7440-36-0, Antimony, uses 7440-39-3, Barium, uses 7440-47-3, Chromium, uses 7440-48-4, Cobalt, uses 7440-50-8, Copper, uses 7440-56-4, Germanium, uses 7440-57-5, Gold, uses 7440-66-6, Zinc, uses 7440-70-2, Calcium, uses 7440-74-6, Indium, uses 9002-86-2, **PVC** 9002-88-4, **Polyethylene** 9003-07-0, **Polypropylene** 24937-78-8, **Ethylene vinyl acetate copolymer** 25038-59-9, uses 25067-34-9, **Ethylene vinyl alcohol copolymer**

RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)
(**anodes** for secondary lithium batteries)

L56 ANSWER 11 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2004:162063 HCAPLUS Full-text

DN 140:206584

TI Method of manufacturing printed circuit board and multi-layered pcb

IN Lee, Hyuek Jae; Yu, Jin

PA Korea Advanced Institute of Science and Technology, S. Korea

SO U.S. Pat. Appl. Publ., 6 pp.

CODEN: USXXCO

DT Patent

LA English

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	US 2004035711	A1	20040226	US 2002-231052	20020830
	US 6902660	B2	20050607		
	KR 2004017478	A	20040227	KR 2002-49550	20020821
PRAI	KR 2002-49550	A	20020821		

AB Disclosed is a fabrication method of a printed circuit board, consisting of plating a metal on a pattern-formed metallic substrate to form a conductive metal line; forming a polymer layer as a base substrate over the conductive metal line-formed metallic substrate and drying the formed polymer layer; forming a via hole to the polymer layer, followed by plugging the formed via hole by electroplating; and removing the metallic substrate. The method is advantageous in terms of maximum efficiency of use of the surface area of PCB, and fineness and high integration of circuits because of not requiring an addnl. etching process.

IC ICM C25D005-02

INCL 205125000; 205131000; 205205000

CC 72-8 (Electrochemistry)

Section cross-reference(s): 38

ST printed circuit board **multilayered polymer metal** electroplating

IT Multilayers

(manufacturing multi-layered printed circuit board)

IT **Polyimides**, uses

Polymers, uses

RL: NUU (Other use, unclassified); USES (Uses)

(manufacturing multi-layered printed circuit board comprising)

IT **Electrodeposition**

(manufacturing multi-layered printed circuit board using)

IT Printed circuit boards

(manufacturing printed circuit board and multi-layered pcb)
IT Laser radiation
(use as substrate in manufacturing multi-layered printed circuit board)
IT Photoresists
(use in manufacturing multi-layered printed circuit board)
IT 7440-31-5P, Tin, processes 7440-47-3P, Chromium, processes 7440-50-8P,
Copper, processes 7440-57-5P, Gold, processes
RL: CPS (Chemical process); PEP (Physical, engineering or chemical
process); PNU (Preparation, unclassified); PREP (Preparation); PROC
(Process)
(manufacturing multi-layered printed circuit board using electroplating of)
IT 12597-68-1, Stainless steel, uses
RL: CPS (Chemical process); DEV (Device component use); NUU (Other use,
unclassified); PEP (Physical, engineering or chemical process); PROC
(Process); USES (Uses)
(use as substrate in manufacturing multi-layered printed circuit board)
IT 7429-90-5, Aluminum, uses 7440-02-0, Nickel, uses
RL: CPS (Chemical process); DEV (Device component use); PEP (Physical,
engineering or chemical process); RCT (Reactant); PROC (Process); RACT
(Reactant or reagent); USES (Uses)
(use as substrate in manufacturing multi-layered printed circuit board)
RE.CNT 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 12 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2004:32458 HCAPLUS Full-text

DN 140:103458

TI Films with **bilayered metals** formed by vapor deposition
and **electrodeposition**, their manufacture, and electronic devices
using such films

IN Miyake, Toru; Suzuki, Takashi; Harada, Hiroshi

PA Toyo Metallizing Co., Ltd., Japan

SO Jpn. Kokai Tokkyo Koho, 9 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 2004009357	A	20040115	JP 2002-162640	20020604
PRAI	JP 2002-162640		20020604		

AB Film comprising a **metal** vapor deposition **layer**, a 0.5-0.9 μm -thick
electroplated elec. conductive **metal layer**, and a <20 μm -thick elec.
insulating layer in the order is claimed. The insulating layer may comprise
polyimides, epoxy resins, or their mixts. or may optionally be thermotropic
liquid crystal polymer. The said films are prepared by formation of a release
layer, the **metal layers** by vapor deposition and electroplating, an elec.
insulating polymer layer by coating, on a plastic support which is then
removed from the release layer. Electronic devices comprising the said films
are also claimed. Crease-free films with high surface smoothness are
obtained.

IC ICM B32B015-04

ICS C23C014-06; C23C028-00; C25D001-22; H05K001-09

CC 76-14 (Electric Phenomena)

Section cross-reference(s): 56

ST **metal multilayered** film surface smoothness; electronic
device **metal multilayered** film; vapor deposition
metal layer multilayered film; electroplated
conductive **metal layer multilayered** film;
thermotropic liq crystal **polymer metal**

KATHLEEN FULLER EIC1700 571/272-2505

- multilayered** film; insulator outermost coating **metal multilayered** film
- IT Electric insulators
(coatings; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT Epoxy resins, uses
Polyimides, uses
RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)
(elec. insulators; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT Capacitors
(film; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT **Polyesters**, uses
RL: NUU (Other use, unclassified); USES (Uses)
(films, released support layer in; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT Printed circuit boards
(manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT Vapor deposition process
(**metal layer** formed by; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT **Electrodeposits**
(**metal layer**; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT Films
(multilayer; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT Liquid crystals, polymeric
(thermotropic; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT 288589-99-1, Uptite UPA-N111
RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)
(insulation layer; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT 644975-79-1, Lumirror T 70D 644976-15-8, Lumirror R 72
RL: NUU (Other use, unclassified); USES (Uses)
(released support layer in; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)
- IT 7440-50-8, Copper, uses
RL: DEV (Device component use); TEM (Technical or engineered material use); USES (Uses)
(vapor deposition, electroplating; manufacture of films with **bilayered metals** and insulation **overlayers** for electronic devices)

L56 ANSWER 13 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2004:20184 HCAPLUS Full-text

DN 140:86047

TI **Metal-laminated multilayer** film capacitors with good contact strength and current and moisture resistance, and their

manufacture
 IN Kubo, Yasuhiro; Nishikawa, Shigeyoshi; Mori, Takashi
 PA Nichicon Corp., Japan
 SO Jpn. Kokai Tokkyo Koho, 14 pp.
 CODEN: JKXXAF
 DT Patent
 LA Japanese
 FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 2004006495	A	20040108	JP 2002-159564	20020531
PRAI	JP 2002-159564		20020531		

AB The film capacitor is manufactured by (A) vapor-depositing Al on dielec. resin films, (B) laminating them, (C) cutting into a stick shape, (D) chemical dry-etching the resins on the cutting side using activated plasma gases, and (E) thermal-spraying metals on the etched surface for forming extraction **electrodes**.

IC ICM H01G004-18
 ICS H01G004-30; H01G004-24

CC 76-10 (Electric Phenomena)

ST film capacitor aluminum resin laminate etching; extn **electrode**
 thermal spraying multilayer capacitor

IT Etching
 (dry, of resin **layers**; **metal**-laminated
multilayer film capacitors with good contact strength and
 current and moisture resistance)

IT Capacitors
 (film; **metal**-laminated **multilayer** film capacitors
 with good contact strength and current and moisture resistance)

IT Acrylic polymers, processes
Polyesters, processes
 Polythiophenylenes
 RL: CPS (Chemical process); DEV (Device component use); PEP (Physical,
 engineering or chemical process); PROC (Process); USES (Uses)
 (**metal**-laminated **multilayer** film capacitors with
 good contact strength and current and moisture resistance)

IT Capacitors
 (**multilayer**; **metal**-laminated **multilayer**
 film capacitors with good contact strength and current and moisture
 resistance)

IT Coating process
 (thermal spraying, forming extraction **electrodes** with;
metal-laminated **multilayer** film capacitors with good
 contact strength and current and moisture resistance)

IT 25230-87-9
 RL: CPS (Chemical process); DEV (Device component use); PEP (Physical,
 engineering or chemical process); PROC (Process); USES (Uses)
 (assumed monomers; **metal**-laminated **multilayer** film
 capacitors with good contact strength and current and moisture
 resistance)

IT 1344-28-1, Alumina, uses 7631-86-9, Silica, uses
 RL: DEV (Device component use); USES (Uses)
 (coating Al **layer** with; **metal**-laminated
multilayer film capacitors with good contact strength and
 current and moisture resistance)

IT 77-73-6DP, Dicyclopentadiene, diacrylates, **polymers**
 RL: CPS (Chemical process); DEV (Device component use); IMF (Industrial
 manufacture); PEP (Physical, engineering or chemical process); PREP
 (Preparation); PROC (Process); USES (Uses)
 (**metal**-laminated **multilayer** film capacitors with

good contact strength and current and moisture resistance)
 IT 24968-11-4, **Polyethylene** naphthalate 25038-59-9, PET polymer, processes
 RL: CPS (Chemical process); DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
 (metal-laminated **multilayer** film capacitors with good contact strength and current and moisture resistance)
 IT 7429-90-5, Aluminum, uses
 RL: DEV (Device component use); USES (Uses)
 (vapor-deposited; metal-laminated **multilayer** film capacitors with good contact strength and current and moisture resistance)

L56 ANSWER 14 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2003:17751 HCAPLUS Full-text

DN 138:42089

TI Packaging methods and fabrication techniques for making electrochemical cells and multicell batteries

IN Klein, Martin G.; Ralston, Paula; Plivelich, Robert

PA Electro Energy, Inc., USA

SO U.S., 20 pp.

CODEN: USXXAM

DT Patent

LA English

FAN, CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	US 6503658	B1	20030107	US 2001-902871	20010711
	US 2003013015	A1	20030116		
	CA 2453558	A1	20030123	CA 2002-2453558	20020628
	WO 2003007415	A1	20030123	WO 2002-US20368	20020628
	W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, OM, PH, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VN, YU, ZA, ZM, ZW				
	RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG				
AU	2002322335	A1	20030129	AU 2002-322335	20020628
EP	1419549	A1	20040519	EP 2002-756320	20020628
	R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR				
JP	2004523091	T	20040729	JP 2003-513073	20020628
CN	1620735	A	20050525	CN 2002-817670	20020628
RU	2298264	C2	20070427	RU 2004-103804	20020628
TW	571457	B	20040111	TW 2002-91115341	20020710
US	2003138691	A1	20030724	US 2003-337816	20030106
US	6887620	B2	20050503		
PRAI	US 2001-902871	A	20010711		
WO	2002-US20368	W	20020628		

AB The bipolar electrochem. battery of the invention comprises: a stack of at least two electrochem. cells elec. arranged in series with the pos. face of each cell contacting the neg. face of an adjacent cell, wherein each of the cells comprises (a) a neg. **electrode**; (b) a pos. **electrode**; (c) a separator between the **electrodes**, wherein the separator includes an electrolyte; (d) a first elec. conductive lamination comprising a first inner **metal layer** and a first **polymeric** outer

layer, the first polymeric outer layer having at least one perforation therein to expose the first inner metal layer, the first elec. conductive lamination being in elec. contact with the outer face of the neg. electrode; and (e) a second elec. conductive lamination comprising a second inner metal layer and a second polymeric outer layer, the second polymeric outer layer having at least one perforation therein to expose the second inner metal layer, the second elec. conductive lamination being in elec. contact with the outer face of the pos. electrode; wherein the first and second laminations are sealed peripherally to each other to form an enclosure including the electrodes, the separator and the electrolyte.

IC ICM H01M010-18
ICS H01M006-48; H01M006-00
INCL 429210000; 429157000; 429162000; 429124000; 429127000; 429082000;
029623100; 029623300
CC 52-2 (Electrochemical, Radiational, and Thermal Energy
Technology)
Section cross-reference(s): 72
ST battery bipolar fabrication packaging method; electrochem cell fabrication
packaging method
IT Epoxy resins, uses
Tar
RL: TEM (Technical or engineered material use); USES (Uses)
(binder; packaging methods and fabrication techniques for making
electrochem. cells and multicell batteries)
IT Rubber, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(cement, binder; packaging methods and fabrication techniques for
making electrochem. cells and multicell batteries)
IT Electric apparatus
(electrochem.; packaging methods and fabrication techniques for making
electrochem. cells and multicell batteries)
IT Polysulfones, uses
RL: TEM (Technical or engineered material use); USES (Uses)
(layer; packaging methods and fabrication techniques for making
electrochem. cells and multicell batteries)
IT Battery anodes
Battery cathodes
Compression
Packaging process
Primary batteries
Secondary batteries
(packaging methods and fabrication techniques for making electrochem.
cells and multicell batteries)
IT Hydrides
Rare earth alloys
RL: DEV (Device component use); USES (Uses)
(packaging methods and fabrication techniques for making electrochem.
cells and multicell batteries)
IT Cement
(rubber, binder; packaging methods and fabrication techniques for
making electrochem. cells and multicell batteries)
IT 1309-42-8, Magnesium hydroxide 1309-48-4, Magnesium oxide, uses
1310-65-2, Lithium hydroxide 1313-99-1, Nickel oxide nio, uses
1344-69-0, Copper hydroxide 1344-70-3, Copper oxide 7439-95-4,
Magnesium, uses 7439-96-5, Manganese, uses 7440-48-4, Cobalt, uses
7782-44-7, Oxygen, uses 11104-61-3, Cobalt oxide 11113-74-9, Nickel
hydroxide 11129-60-5, Manganese oxide 12057-24-8, Lithium oxide, uses
12626-88-9, Manganese hydroxide 12653-71-3, Mercury oxide 12672-51-4,
Cobalt hydroxide 12673-77-7, Silver hydroxide 20667-12-3, Silver oxide

39321-13-6, Mercury hydroxide
RL: DEV (Device component use); USES (Uses)
(cathodes; packaging methods and fabrication techniques for making electrochem. cells and multicell batteries)

IT 7429-90-5, Aluminum, uses 7439-93-2, Lithium, uses 7440-02-0, Nickel, uses 7440-22-4, Silver, uses 7440-50-8, Copper, uses 9002-86-2, Polyvinyl chloride 9002-88-4, **Polyethylene** 9003-07-0, **Polypropylene** 12597-69-2, Steel, uses

RL: TEM (Technical or engineered material use); USES (Uses)
(layer; packaging methods and fabrication techniques for making electrochem. cells and multicell batteries)

IT 1333-74-0, Hydrogen, uses 7439-89-6, Iron, uses 7440-43-9, Cadmium, uses 7440-66-6, Zinc, uses 7580-67-8, Lithium hydride 37187-84-1, Nickel hydride 37251-25-5, Copper hydride 64296-66-8, Iron hydride

RL: DEV (Device component use); USES (Uses)
(packaging methods and fabrication techniques for making electrochem. cells and multicell batteries)

IT 7440-44-0, Carbon, uses

RL: MOA (Modifier or additive use); USES (Uses)
(polyvinyl chloride filled with; packaging methods and fabrication techniques for making electrochem. cells and multicell batteries)

RE.CNT 10 THERE ARE 10 CITED REFERENCES AVAILABLE FOR THIS RECORD.
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 15 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2002:633163 HCAPLUS Full-text

DN 137:251236

TI Application of multilayer or composite coating on dielectric fibers or sheets from electroplating baths

IN Popov, G. P.

PA Russia

SO Russ., No pp. given
CODEN: RUXXE7

DT Patent

LA Russian

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	RU 2177051	C1	20011220	RU 2001-105400	20010227
PRAI	RU 2001-105400		20010227		

AB The dielec. fibers, cloth, or sheet substrates are pretreated by 2-stage activation with washing and sulfidizing, and then are coated with a composite **layer** by **metalizing** from electroplating bath. The composite is based on Ni or Ni-alloy coating containing dispersed particles selected from: Mo and/or W sulfides; Cd, Zn, Ta, and/or Mo selenides; oxides of Nb, Al, and/or Si; and/or diamond or graphite. The dielec. **polymer** fibers with **multilayer** coating are suitable for protection against the effects of magnetic fields, electromagnetic radiation, or cosmic-ray bombardment.

IC ICM C23C018-16

ICS C23C028-00; C25D005-54

CC 56-4 (Nonferrous Metals and Alloys)

Section cross-reference(s): 40

ST polymer fiber activation electroplating nickel alloy composite; multilayer coating dielec fabric activation electroplating

IT Metal matrix composites

(Ni-alloy; application of multilayer or composite coating on dielec. fabric by electroplating)

IT Synthetic polymeric fibers, processes

RL: EPR (Engineering process); PEP (Physical, engineering or chemical process); PROC (Process)

(coating of; application of multilayer or composite coating on dielec. fibers by electroplating)

IT **Polyamides**, uses
 RL: TEM (Technical or engineered material use); USES (Uses)
 (fibers, coating of; multilayer or composite coating applied on activated dielec. fibers by electroplating)

IT **Shields**
 (flexible, coated fabric for; application of multilayer or composite coating on dielec. fabric by electroplating)

IT **Electrodeposition**
 (multilayer; application of multilayer or composite coating on dielec. fibers by electroplating)

IT **Sulfidation**
 (of fibers, for coating; application of multilayer or composite coating on dielec. fibers by electroplating)

IT 7440-48-4D, Cobalt, salts 7440-50-8D, Copper, salts 7440-66-6D, Zinc, salts 14798-03-9D, Ammonium, salts
 RL: CAT (Catalyst use); USES (Uses)
 (aqueous, activation solution with; multilayer or composite coating applied on activated dielec. fibers by electroplating)

IT 1306-24-7, Cadmium selenide, uses 1315-09-9, Zinc selenide 1317-33-5, Molybdenum disulfide, uses 1344-28-1, Alumina, uses 7631-86-9, Silica, uses 7782-40-3, Diamond, uses 7782-42-5, Graphite, uses 12039-55-3, Tantalum diselenide 12058-18-3, Molybdenum selenide 12138-09-9, Tungsten disulfide 12627-00-8, Niobium oxide
 RL: MOA (Modifier or additive use); USES (Uses)
 (dispersed, composite coating with; multilayer or composite coating applied on activated dielec. fibers by electroplating)

IT 7440-02-0, Nickel, uses
 RL: TEM (Technical or engineered material use); USES (Uses)
 (electroplating with; application of multilayer or composite coating on dielec. fibers by electroplating)

IT 25038-54-4, Capron, uses
 RL: TEM (Technical or engineered material use); USES (Uses)
 (fibers, coating of; multilayer or composite coating applied on activated dielec. fibers by electroplating)

L56 ANSWER 16 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN
 AN 2002:51807 HCAPLUS Full-text
 DN 136:94638
 TI Making encapsulated organic electronic devices
 IN McCormick, Fred B.; Baude, Paul F.; Vernstrom, George D.
 PA 3M Innovative Properties Company, USA
 SO PCT Int. Appl., 33 pp.
 CODEN: PIXXD2
 DT Patent
 LA English
 FAN.CNT 1

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2002005361	A1	20020117	WO 2000-US31393	20001115
W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CR, CU, CZ, DE, DK, DM, DZ, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, TZ, UA, UG, UZ, VN, YU, ZA, ZW				
RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZW, AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR, BF,				

BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG
 US 6867539 B1 20050315 US 2000-614993 20000712
 EP 1299913 A1 20030409 EP 2000-989200 20001115
 R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
 IE, SI, LT, LV, FI, RO, MK, CY, AL, TR
 JP 2004503066 T 20040129 JP 2002-509116 20001115
 US 2005129841 A1 20050616 US 2005-35517 20050114
 PRAI US 2000-614993 A 20000712
 WO 2000-US31393 W 20001115

AB The invention provides methods for making encapsulated organic electronic devices (OED) including organic LEDs (OLED). The present invention can provide a robust OED device by means of in situ edge sealing enhancing structural integrity and device lifetime. The edge sealing is provided by using an adhesive component applied to a substrate prior to OED element deposition. A thin layer of an adhesive (pressure sensitive adhesive, hot melt, or curable) is applied to release liner, openings are cut in the adhesive/liner composite, then the composite is adhered to an **electrode**-coated substrate. Alternatively, an adhesive may be applied directly onto the **electrode**-coated substrate, e.g., by printing in a desired pattern, optionally partially cured or dried, then covered with ≥ 1 liners that act as a mask during deposition of the OLED elements. Another method would be to prepare a blank liner with a patterned adhesive, then die cut openings complementary to the adhesive pattern in the liner to allow deposition of OLED elements once the adhesive/liner is placed on the substrate.

IC ICM H01L051-20
 ICS H01L051-40; H05B033-04

CC 76-3 (Electric Phenomena)
 Section cross-reference(s): 38

ST encapsulated org electronic device prepn

IT Electric conductors
 (adhesive, thermal, elec.; making encapsulated organic electronic devices)

IT Electron beam evaporation
 (alumina layer; making encapsulated organic electronic devices)

IT Siloxanes (nonpolymeric)
 RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
 (coated on metal foil as adhesive-coated liner; making encapsulated organic electronic devices)

IT **Polyesters**, processes
 RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
 (coated with siloxanes or fluorocarbons as adhesive-coated liner; making encapsulated organic electronic devices)

IT Adhesives
 (conductive, thermal, elec.; making encapsulated organic electronic devices)

IT Adhesives
 (curable; making encapsulated organic electronic devices)

IT Fluoropolymers, processes
 RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
 (film as adhesive-coated liner; making encapsulated organic electronic devices)

IT Hydrocarbons, processes
 RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
 (fluoro, coated on metal foil as adhesive-coated liner; making encapsulated organic electronic devices)

IT Electric contacts
 Electroluminescent devices

Encapsulation
Lamps (nonelectric)
Microelectronic devices
Release coatings
Sealing
Shadow masks
(making encapsulated organic electronic devices)

IT Foils
(**metal** as protective **layer**; making encapsulated organic electronic devices)

IT **Multilayers**
(**polymer** as protective layer; making encapsulated organic electronic devices)

IT Films
(polymeric; making encapsulated organic electronic devices)

IT Adhesives
(pressure-sensitive; making encapsulated organic electronic devices)

IT Glass, uses
RL: DEV (Device component use); USES (Uses)
(thin flexible as protective layer; making encapsulated organic electronic devices)

IT 7789-24-4, Lithium fluoride; uses
RL: DEV (Device component use); USES (Uses)
(LiF/Al cathode; making encapsulated organic electronic devices)

IT 9003-07-0, **Polypropylene**
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(adhesive-coated liner; making encapsulated organic electronic devices)

IT 126213-51-2, Poly(ethylenedioxythiophene)
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(conductive polymer in light emitting construction; making encapsulated organic electronic devices)

IT 1314-13-2, Zinc oxide, uses 7429-90-5, Aluminum, uses 7439-93-2, Lithium, uses 7439-95-4, Magnesium, uses 7440-19-9, Samarium, uses 7440-22-4, Silver, uses 7440-39-3, Barium, uses 7440-57-5, Gold, uses 7440-65-5, Yttrium, uses 7440-70-2, Calcium, uses 50926-11-9, ITO 53740-87-7
RL: DEV (Device component use); USES (Uses)
(counter **electrode**; making encapsulated organic electronic devices)

IT 1344-28-1, Alumina, processes
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(electron beam evaporation on ITO; making encapsulated organic electronic devices)

IT 1332-29-2, Tin oxide
RL: DEV (Device component use); USES (Uses)
(fluorine, counter **electrode**; making encapsulated organic electronic devices)

IT 123847-85-8, α -NPD
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(hole transport layer in light emitting construction; making encapsulated organic electronic devices)

IT 147-14-8, Copper phthalocyanine 155306-71-1, C545T
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(in light emitting construction; making encapsulated organic electronic devices)

IT 2085-33-8, Tris(8-hydroxyquinolinato)aluminum
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(light emitting layer; making encapsulated organic electronic devices)
RE.CNT 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS RECORD
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 17 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 2001:245794 HCAPLUS Full-text

DN 135:27559

TI **Multilayer** planarization of **polymer** dielectrics

AU Chiniwalla, Punit; Manepalli, Rahul; Farnsworth, Kimberly; Boatman, Mary; Dusch, Brian; Kohl, Paul; Bidstrup-Allen, Sue Ann

CS School of Chemical Engineering, Georgia Institute of Technology, Atlanta, GA, 30332-0100, USA

SO IEEE Transactions on Advanced Packaging (2001), 24(1), 41-53
CODEN: ITAPFZ; ISSN: 1521-3323

PB Institute of Electrical and Electronics Engineers

DT Journal

LA English

AB Polymers are widely used in the microelectronics industry as thin-film interlevel dielects. **layers** between **metal** lines, as passivation layers on semiconductor devices and in various packaging applications. As multiple layers of polymer and patterned metal are constructed, the ability of these polymers to planarize topog. features becomes increasingly important. The degree of planarization (DOP) for five com. available polymers was examined for three different structural configurations with the intent of simulating practical applications. Specifically, this study studies single layer planarization, multiple coat planarization, and planarization of metal lines patterned on a polymer base. This study also examines the effects of orientation of the metal structure to polymer flow during spin casting and location on the wafer. The polymers were selected to study different polymer chemistries frequently used in the microelectronics industry. The underlying structures were fabricated using standard photolithog. and electroplating techniques. Feature dimensions include 25-200 μm line spacings and widths with the polymer overcoat thickness being twice the height of the underlying structures.

CC 76-10 (Electric Phenomena)

Section cross-reference(s): 38, 66

ST **polymer** spin casting **multilayer** planarization dielec film

IT Dielectric films

Electrodeposition

Multilayers

Photolithography

(**multilayer** planarization of **polymer** dielects.)

IT **Polyimides**, processes

Polymers, processes

RL: PEP (Physical, engineering or chemical process); TEM (Technical or engineered material use); PROC (Process); USES (Uses)

(**multilayer** planarization of **polymer** dielects.)

IT Coating process

(spin; **multilayer** planarization of **polymer** dielects.)

IT 124221-30-3, DVS-BCB 3022-57

RL: PEP (Physical, engineering or chemical process); TEM (Technical or engineered material use); PROC (Process); USES (Uses)

(DVS-BCB 3022-57; **multilayer** planarization of **polymer** dielects.)

IT 7440-32-6, Titanium, processes 7440-50-8, Copper, processes

KATHLEEN FULLER EIC1700 571/272-2505

29319-22-0, PI 2611 157243-45-3; Ultradel 7501 182371-85-3, PI 2734
222050-75-1, LMB 7081

RL: PEP (Physical, engineering or chemical process); TEM (Technical or
engineered material use); PROC (Process); USES (Uses)

(**multilayer** planarization of **polymer** dielects.)

RE.CNT 12 THERE ARE 12 CITED REFERENCES AVAILABLE FOR THIS RECORD
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 18 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 1999:34341 HCAPLUS Full-text

DN 130:82163

TI Method of manufacturing passive elements using conductive polypyrrole
formulations

IN Murphy, Oliver J.; Hitchens, G. Duncan; Hodko, Dalibor; Clarke, Eric T.;
Miller, David L.; Parker, Donald L.

PA Lynntech, Inc., USA

SO U.S., 24 pp., Cont.-in-part of U.S. 5,545,308.

CODEN: USXXAM

DT Patent

LA English

FAN.CNT 6

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 5855755	A	19990105	US 1996-630063	19960412
US 5545308	A	19960813	US 1995-491625	19950619
US 6210537	B1	20010403	US 1995-492235	19950619
WO 9739383	A1	19971023	WO 1997-US6047	19970411

W: AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE,
DK, EE, ES, FI, GB, GE, HU, IL, IS, JP, KE, KG, KP, KR, KZ, LC,
LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT,
RO, RU, SD, SE, SG, SI, SK, TJ, TM, TR, TT, UA, UG, US, UZ, VN

RW: GH, KE, LS, MW, SD, SZ, UG, AT, BE, CH, DE, DK, ES, FI, FR, GB,
GR, IE, IT, LU, MC, NL, PT, SE, BF, BJ, CF, CG, CI, CM, GA, GN,
ML, MR, NE, SN, TD, TG

AU 9728009	A	19971107	AU 1997-28009	19970411
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EP 832448	A1	19980401	EP 1997-922296	19970411
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EP 832448	B1	20010711		
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R: AT, BE, CH, DE, ES, FR, GB, IT, LI, NL, SE

AT 203111	T	20010715	AT 1997-922296	19970411
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US 5948232	A	19990907	US 1997-881107	19970623
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PRAI US 1995-491625	A2	19950619		
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US 1995-492235	A2	19950619		
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US 1996-630063	A1	19960412		
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WO 1997-US6047	W	19970411		
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AB The present invention provides electronically conducting polymer films formed
from photosensitive formulations of pyrrole and an electron acceptor that have
been selectively exposed to UV light, laser light, or electron beams. The
formulations may include photoinitiators, flexibilizers, solvents and the
like. These formulations can be used to manufacture multichip modules on
typical multichip module substrates, such as alumina, fiberglass epoxy,
silicon and **polyimide**. The formulations and methods of the invention enable
the formation of passive electronic circuit elements such as resistors,
capacitors and inductors in multichip modules or printed wiring boards.

IC ICM C25D005-02

ICS C25D005-54; C08F002-48; B21F041-00

INCL 205122000

CC 36-6 (Physical Properties of Synthetic High Polymers)

Section cross-reference(s): 38, 72, 73

ST conductive polypyrrole formulation passive element electronic device;
photopolymn photoinitiator flexibilizer solvent resistor capacitor

indicator
IT Electron beams
Heat treatment
IR laser radiation
Plasticizers
UV radiation
(in manufacturing passive elements using conductive polypyrrole formulations)
IT Solvents
Surfactants
(manufacturing passive elements using conductive polypyrrole formulations using)
IT Capacitors
Electric apparatus
Indicators
Printed circuit boards
Resistors
(manufacturing using conductive polypyrrole formulations)
IT Electric conductivity
Multilayers
Surface structure
(of conducting **polymer** films in manufacturing passive elements using conductive polypyrrole formulations)
IT Electric resistance
Thickness
(of conducting polymer films-resistors)
IT **Electrodeposition**
(of of **metal** electroconductive **layer** and dielec. material layer in manufacturing passive elements using conductive polypyrrole formulations)
IT Polymerization
(photopolymn.; manufacturing passive elements using conductive polypyrrole formulations obtained by)
IT Coating process
(spin; manufacturing passive elements using conductive polypyrrole formulations using)
IT Glass fibers, properties
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
(substrate in manufacturing passive elements using conductive polypyrrole formulations)
IT 151-41-7 25155-30-0, Sodium dodecylbenzenesulfonate 28605-98-3, Sodium dodecylbenzenesulfate
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
(flexibilizer in manufacturing passive elements using conductive polypyrrole formulations)
IT 62-53-3, Aniline, properties 62-53-3D, Aniline, derivative
RL: PRP (Properties); RCT (Reactant); RACT (Reactant or reagent)
(forming dielec. layer in solid state electrolytic capacitors using)
IT 7440-05-3, Palladium, properties 7440-50-8, Copper, properties
RL: FMU (Formation, unclassified); PRP (Properties); FORM (Formation, nonpreparative)
(forming electroconductive layer in solid state electrolytic capacitors by **electrodeposition** of)
IT 30604-81-0, Polypyrrole
RL: FMU (Formation, unclassified); NUU (Other use, unclassified); PRP (Properties); FORM (Formation, nonpreparative); USES (Uses)
(manufacturing passive elements using conductive polypyrrole formulations)
IT 7761-88-8, Silver nitrate, properties 14104-20-2, Silver

tetrafluoroborate 16836-95-6, Silver tosylate
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
(manufacturing passive elements using conductive polypyrrole formulations and)
IT 14797-55-8, Nitrate, properties 14797-65-0, Nitrite, properties
14797-73-0, Perchlorate 14874-70-5, Tetrafluoroborate 16722-51-3, Tosylate, properties
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
(manufacturing passive elements using conductive polypyrrole formulations and
dopant anion such as)
IT 1271-29-0, Titanocene 12125-80-3, Ferrocenium 12176-31-7,
(η^6 -Benzene)(η^5 -cyclopentadienyl)iron(II) hexafluorophosphate
104558-94-3, Cyacure UVI 6974 104558-95-4, Cyacure UVI 6990
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
(photoinitiator in manufacturing passive elements using conductive polypyrrole formulations)
IT 109-97-7, Pyrrole 109-97-7D, Pyrrole, derivative
RL: PRP (Properties); RCT (Reactant); RACT (Reactant or reagent)
(polymerization for manufacturing passive elements using conductive polypyrrole formulations)
IT 1344-28-1, Alumina, properties
RL: DEV (Device component use); PRP (Properties); USES (Uses)
(substrate in manufacturing passive elements using conductive polypyrrole formulations)
IT 75-05-8, Acetonitrile, properties
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
(using in manufacturing passive elements using conductive polypyrrole formulations)
RE.CNT 14 THERE ARE 14 CITED REFERENCES AVAILABLE FOR THIS RECORD
ALL CITATIONS AVAILABLE IN THE RE FORMAT

L56 ANSWER 19 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 1997:587852 HCAPLUS Full-text

DN 127:286978

TI **Multilayer metal-electroplated polymer**

molding with good surface smoothness and wire bondability, its manufacture, and electronic part

IN Akeda, Tomoyuki

PA Polyplastics Co., Ltd., Japan

SO Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 09228093	A	19970902	JP 1996-30348	19960219
	JP 3529215	B2	20040524		
PRAI	JP 1996-30348		19960219		

AB The polymer molding is manufactured by forming a low-stress electroplated layer with internal stress ≤ 1.5 kg/mm² and forming an uppermost electroplated layer using a bath with large leveling effect. The molding has the 1st electroplated layer with internal stress ≤ 1.5 kg/mm² and the uppermost electroplated layer with surface roughness ≤ 10 μ m. The electronic part is obtained by laminating an electronic element on the molding using a wire bonding method. The molding showed good surface smoothness and wire bondability.

IC ICM C25D005-10
ICS C25D005-56; C23C028-02
CC 76-14 (Electric Phenomena)
Section cross-reference(s): 38, 56, 72
ST metal electroplated polymer molding electronic part; wire bondability
metal electroplated polymer molding; surface smoothness metal
electroplated polymer molding
IT **Electrodeposition**
Liquid crystals, **polymeric**
Printed circuit boards
(**multilayer metal-electroplated polymer**
molding with good wire bondability for electronic part)
IT **Polyesters**, uses
RL: DEV (Device component use); USES (Uses)
(substrate; **multilayer metal-electroplated**
polymer molding with good wire bondability for electronic part)
IT 196522-27-7, Cupracid 828A 196522-40-4, Cupracid 828M
RL: MOA (Modifier or additive use); USES (Uses)
(brightening agent; **multilayer metal-electroplated**
polymer molding with good wire bondability for electronic part)
IT 7440-50-8, Copper, processes
RL: DEV (Device component use); PEP (Physical, engineering or chemical
process); PROC (Process); USES (Uses)
(**multilayer metal-electroplated polymer**
molding with good wire bondability for electronic part)
IT 7758-98-7, Copper sulfate, uses
RL: NUU (Other use, unclassified); USES (Uses)
(**multilayer metal-electroplated polymer**
molding with good wire bondability for electronic part)
IT 196522-32-4, Copper Gleam 125
RL: MOA (Modifier or additive use); USES (Uses)
(stress-reducing agent; **multilayer metal**
-electroplated polymer molding with good wire bondability for
electronic part)
IT 116255-48-2, Vectra
RL: DEV (Device component use); USES (Uses)
(substrate; **multilayer metal-electroplated**
polymer molding with good wire bondability for electronic part).

L56 ANSWER 20 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 1997:508513 HCAPLUS Full-text

DN 127:228290

TI Multilayer interconnection circuit boards and manufacturing thereof by
plating circuits and laminating polymer insulators

IN Ito, Daisuke; Sasaki, Masayuki

PA Shinko Electric Industries Co., Ltd., Japan

SO Jpn. Kokai Tokkyo Koho, 6 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	JP 09199850	A	19970731	JP 1996-4485	19960116
PRAI	JP 1996-4485		19960116		

AB The title circuit boards have a multilayer circuit patterns which are formed
via insulator layers on both sides of a substrate and connected between the
patterns through via holes. The manufacturing involves coating an insulative
polymer layer over an internal circuit pattern, **electrodepositing a metallic**
layer on the insulator **layer**, patterning the **metallic layer** by etching, press-

laminating on the patterned **metallic layer** with a Cu-formed polymer insulator layer so as to become the outer metallic film flat surface, and subsequently etching to pattern the outer metallic film to give an outer circuit layer. The fabrication gives the outer circuit pattern and the outer insulator layer an increased adhesion and increased integration.

IC ICM H05K003-46
ICS H05K003-46
CC 76-2 (Electric Phenomena)
Section cross-reference(s): 38, 56
ST interconnection circuit board **electrodeposition** copper
patterning; **polymer** insulator **multilayer** circuit
adhesion integration; leveling multilayer circuit board press lamination
IT Epoxy resins, properties
Polyimides, properties
RL: PEP (Physical, engineering or chemical process); POF (Polymer in
formulation); PRP (Properties); PROC (Process); USES (Uses)
(elec. insulator; multilayer interconnection circuit boards and
manufacturing
thereof by plating circuits and laminating polymer insulators)
IT Adhesion, physical
Electrodeposition
Integrated circuits
Interconnections (electric)
(multilayer interconnection circuit boards and manufacturing thereof by
plating circuits and laminating polymer insulators)
IT Printed circuit boards
(multilayer; multilayer interconnection circuit boards and manufacturing
thereof by plating circuits and laminating polymer insulators)
IT Coating process
(**polymer** insulator; **multilayer** interconnection
circuit boards and manufacturing thereof by plating circuits and laminating
polymer insulators)
IT Electric insulators
(**polymer**; **multilayer** interconnection circuit boards
and manufacturing thereof by plating circuits and laminating polymer
insulators)
IT 7440-50-8P, Copper, properties
RL: PEP (Physical, engineering or chemical process); PNU (Preparation,
unclassified); PRP (Properties); PREP (Preparation); PROC (Process)
(elec. circuits; multilayer interconnection circuit boards and
manufacturing
thereof by plating circuits and laminating polymer insulators)

L56 ANSWER 21 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 1995:377353 HCAPLUS Full-text

DN 122:303870

TI M4CMS (thin film Multi-MMic Multi-IC Modules) for microwave applications

AU Feurer, Ernst; Oppermann, Martin; Holl, Bruno

CS Deutsche Aerospace (Dasa), Ulm, 89077, Germany

SO Proceedings of SPIE-The International Society for Optical Engineering
(1994), 2369(27th International Symposium on Microelectronics, 1994),
49-53

CODEN: PSISDG; ISSN: 0277-786X

DT Journal

LA English

AB Microwave Transmit/Receive (T/R) modules for modern radar applications were
realized with multilayer integration technol. The M4-multilayer is designed
and fabricated in thin film technol. on Al2O3 ceramic substrates and offers a
high order of complexity for radio frequency (rf) circuits up to 20 GHz.
Single-face and double-face structured and populated MCM substrates are

presented. Microstrip lines with integrated thin film resistors in combination with the dielec. spaced ground layer on the opposite side define the radiofrequency layer on top of the substrate. The multilayer logic control unit consists of three **metal layers** (ground-, x-, y-conductor plane), each separated by patterned polymeric dielects. (**polyimide**, benzocyclobutene). This paper describes the necessary technol. steps for high performance in thin film multilayer technol. in regard to cost driven microwave applications.

CC 76-3 (Electric Phenomena)
Section cross-reference(s): 57
ST radar multilayer multimodule technol alumina
IT Laser radiation
(drilling; multilayer multimodule technol. for radar)
IT **Polymers**, processes
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(insulating; **multilayer** multimodule technol. for radar)
IT Annealing
Electrodeposition and Electroplating
Etching
Lithography
Radar
Sputtering
(multilayer multimodule technol. for radar)
IT **Polyimides**, processes
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(multilayer multimodule technol. for radar)
IT Electric insulators and Dielectrics
(**polymeric**; **multilayer** multimodule technol. for radar)
IT 1344-28-1, Alumina, processes 7440-02-0, Nickel, processes 7440-57-5, Gold, processes 11105-45-6 12642-02-3 124221-30-3D, Benzocyclobutene, **polymers**
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)
(**multilayer** multimodule technol. for radar)

L56 ANSWER 22 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN

AN 1992:44112 HCAPLUS Full-text

DN 116:44112

TI **Multilayer metal** sheets for laminar batteries and manufacture of the batteries

IN Hasuda, Yoshiaki; Horie, Toshio; Ishizawa, Maki

PA Nippon Telegraph and Telephone Corp., Japan

SO Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 03163756	A	19910715	JP 1989-299865	19891120
	JP 2504851	B2	19960605		
PRAI	JP 1989-299865		19891120		

AB The sheets, for use as collectors for sealed laminar batteries having cathodes and **anodes** on the same side of substrate films and separated from each other by an electrolyte, are coated with an epoxy resin layer and ≥ 1 layers of maleic anhydride-containing chlorinated **polyethylene**, optionally mixed with other chlorinated polymers. The batteries are prepared by coating the metal sheets with an epoxy resin, applying ≥ 1 layers of the chlorinated **polyethylene**

- on the coated sheets, and hot pressing the sheets to the substrate films. The sheets have strong bonding with the substrate films.
- IC ICM H01M004-64
ICS H01M002-02; H01M004-66; H01M010-12
- CC 52-2 (**Electrochemical**, Radiational, and Thermal Energy Technology)
Section cross-reference(s): 42
- ST battery **electrode** collector epoxy coating; chlorinated **polyethylene** coating **electrode** collector; maleated **polyethylene** coating **electrode** collector
- IT Epoxy resins, uses
RL: USES (Uses)
(coatings containing layers of, **electrode** current collectors with, lead, for laminar batteries)
- IT Coating materials
(epoxy and maleated chlorinated **polyethylene**, multilayer, lead current collectors with, for laminar batteries)
- IT Batteries, primary
(laminar, manufacture of, lead current collectors with **multilayer polymer** coatings for)
- IT **Electrodes**
(battery, current collectors for, lead, **multilayer polymer**-coated)
- IT 9002-88-4D, **Polyethylene**, chlorinated, maleic anhydride-containing
RL: USES (Uses)
(coatings containing layers of, **electrode** current collectors with, lead, for laminar batteries)
- IT 24937-78-8D, **Ethylene-vinyl** acetate copolymer, chlorinated
RL: USES (Uses)
(coatings containing, **electrode** current collectors with, lead, for laminar batteries)
- IT 7439-92-1, Lead, uses
RL: USES (Uses)
(**electrode** current collectors, **multilayer polymer** coatings for, in laminar batteries)
- L56 ANSWER 23 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN
- AN 1990:80964 HCAPLUS Full-text
- DN 112:80964
- TI Design and optical modulation of electrochromic windows
- AU Dao, Le H.; Nguyen, My T.
- CS Lab. Rech. Mater. Av., Inst. Natl. Rech. Sci., Varennes, QC, J0L 2P0, Can.
- SO Proceedings of the Intersociety Energy Conversion Engineering Conference (1989), 24th(Vol. 4), 1737-41
CODEN: PIECDE; ISSN: 0146-955X
- DT Journal
- LA English
- AB Electrochromic smart windows were fabricated using **anodic** and cathodic layers of **metal** oxides and conducting polymers and ionically conductive polymer electrolyte layers, deposited by electrochem. polymerization and solution casting. Prototype structures include: ITO/polyaniline (I)/PEO/WO3/ITO; SnO2/blue I/poly(2-acrylamido-2-methylpropanesulfonate)/WO3/SnO2, ITO/I/poly(ethyleneimine)/WO3-MO3/ITO; and ITO/I/poly(ethylene glycol methacrylate)-poly(ethylene glycol diacrylate)/WO3/ITO. The transmittance of the all solid-state devices can be controlled within 10-80%, by applying voltage between the bleached state and the colored state.
- CC 52-3 (**Electrochemical**, Radiational, and Thermal Energy Technology)
Section cross-reference(s): 38, 73

- ST electrochromic smart window conducting polymer; polyaniline ITO metal oxide electrochromic window; polyacrylsulfonate polyethyleneimine electrochromic window; **polyethylene glycol acrylate** electrochromic window; indium tin oxide electrochromic window
- IT Electrochromic materials
(conducting polymer and metal oxides, preparation and properties of, for smart windows)
- IT Polyamines
RL: PREP (Preparation)
(ethylenimine, electrolytes, electrochromic window containing, preparation and performance of)
- IT Electric conductors
(polymeric, electrochromic window containing layer of, manufacture and performance of)
- IT Light
(transmission of, by conducting polymer-metal oxide electrochromic **layers**, voltage cycling effect on)
- IT Windows
(variable-transparency, electrochromic, conducting **polymer-metal oxide multilayer**, manufacture and performance of)
- IT 25233-30-1P, Polyaniline
RL: PREP (Preparation)
(electrochromic window containing layer of oxidized and reduced, preparation and performance of)
- IT 1314-35-8, Tungsten oxide (WO3), uses and miscellaneous 11098-99-0, Molybdenum oxide 18282-10-5, Tin oxide (SnO2) 27119-07-9, Poly(2-acrylamido-2-methylpropanesulfonic acid) 37275-78-8, Poly(vinyl alcohol phosphate) 50926-11-9, ITO
RL: USES (Uses)
(electrochromic window containing, preparation and performance of)
- IT 7791-03-9P, Lithium perchlorate (LiClO4) 33454-82-9P
RL: PREP (Preparation)
(electrolytes of polymer and, electrochromic window containing, preparation and performance of)
- IT 108-32-7P, Propylene carbonate 7439-93-2DP, Lithium, PEO complexes 9002-98-6P, Poly(ethylenimine) 25322-68-3DP, PEO, Li complexes 108927-94-2P
RL: PREP (Preparation)
(electrolytes, electrochromic window containing, preparation and performance of)
- L56 ANSWER 24 OF 24 HCAPLUS COPYRIGHT 2007 ACS on STN
- AN 1983:188000 HCAPLUS Full-text
- DN 98:188000
- TI Formation of **bilayer metal polymer-polymer** coatings
- AU Ul'berg, Z. R.; Deinega, Yu. F.; Podol'skaya, V. I.; Nizhnik, Yu. V.; Dvornichenko, G. L.
- CS Inst. Kolloidn. Khim. Khim. Vody im. Dumanskogo, Kiev, USSR
- SO Ukrainskii Khimicheskii Zhurnal (Russian Edition) (1983), 49(2), 168-73
CODEN: UKZHAU; ISSN: 0041-6045
- DT Journal
- LA Russian
- AB The mechanism was studied of the formation of metal-polymer-polymer coatings, especially the characteristics of occurrence of electrochem. reactions on metal-polymer **electrodes** and their role in forming composite coatings. The electrophoretic deposition of finely divided epoxide (E-41, E-30) and

polyester (PE-943B) oligomers on metal-polymer **electrodes** containing these polymers and colloidal Cu particles was studied. The metal-polymer **electrodes** were formed by codeposition of polymer and metal particles according to an electrophoretic-electrochem. method. Polarization curves were plotted with a potential scanning rate of 5 mV/s on a potentiostat, and i - τ curves were plotted under potentiostatic conditions. The corrosion resistance of 2-layer coatings in a chamber with 100% humidity at 40° ams. to 38 days, while 1-layer coatings last 18 days. The 2-layer coatings with prime coats, containing 40-60% Cu, have improved elec. strength.

CC 72-8 (Electrochemistry)

Section cross-reference(s): 38, 42, 66

ST formation **bilayer metal polymer** coating;

electrolytic polarization bilayer coating; copper **polymer bilayer** coating

IT Coating process

(of **bilayer metal polymer-polymer**
)

IT Electrolytic polarization

(of copper and metal-polymer **electrodes** in potassium chloride solution)

IT Coating process

(electrophoretic, of epoxides and **polyesters**)

IT Alkyd resins

RL: PEP (Physical, engineering or chemical process); PROC (Process)
(epoxy, electrophoretic deposition of, on metal-polymer **electrodes**)

IT 7447-40-7, properties

RL: PRP (Properties)

(electrolytic polarization of copper and metal-polymer **electrodes** in solns. containing)

IT 7440-50-8, properties

RL: PRP (Properties)

(electrolytic polarization of, in potassium chloride solution)

IT 25038-59-9, uses and miscellaneous 25068-38-6

RL: PEP (Physical, engineering or chemical process); PROC (Process)
(electrophoretic deposition of, on metal-polymer **electrodes**)

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